

DATA SHEET

74LV86

Quad 2-input EXCLUSIVE-OR gate

Product specification
Supersedes data of 1997 Feb 03
IC24 Data Handbook

1998 Apr 20

Quad 2-input EXCLUSIVE-OR gate

74LV86

FEATURES

- Wide Operating voltage: 1.0 to 5.5 V
- Optimized for low voltage applications: 1.0 to 3.6 V
- Accepts TTL input levels between $V_{CC} = 2.7\text{ V}$ and $V_{CC} = 3.6\text{ V}$
- Typical V_{OLP} (output ground bounce) $< 0.8\text{ V}$ at $V_{CC} = 3.3\text{ V}$, $T_{amb} = 25^{\circ}\text{C}$
- Typical V_{OHV} (output V_{OH} undershoot) $> 2\text{ V}$ at $V_{CC} = 3.3\text{ V}$, $T_{amb} = 25^{\circ}\text{C}$
- Output capability: standard
- I_{CC} category: SSI

DESCRIPTION

The 74LV86 is a low-voltage Si-gate CMOS device that is pin and function compatible with 74HC/HCT86.

The 74LV86 provides the 2-input EXCLUSIVE-OR function.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25^{\circ}\text{C}$; $t_r = t_f \leq 2.5\text{ ns}$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t_{PHL}/t_{PLH}	Propagation delay nA, nB to nY	$C_L = 15\text{ pF}$; $V_{CC} = 3.3\text{ V}$	11	ns
C_I	Input capacitance		3.5	pF
C_{PD}	Power dissipation capacitance per gate	$V_I = \text{GND to } V_{CC}^1$	30	pF

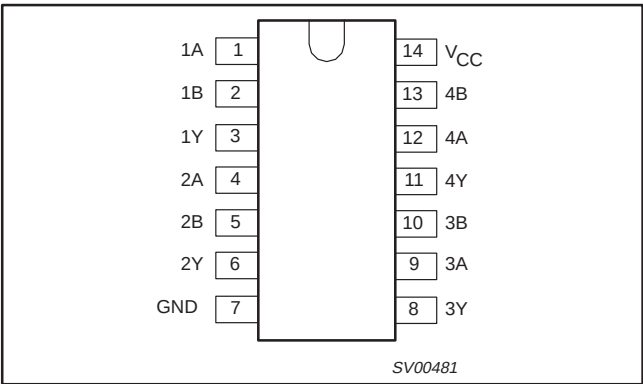
NOTE:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW)
 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$ where:
 f_i = input frequency in MHz; C_L = output load capacitance in pF;
 f_o = output frequency in MHz; V_{CC} = supply voltage in V;
 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

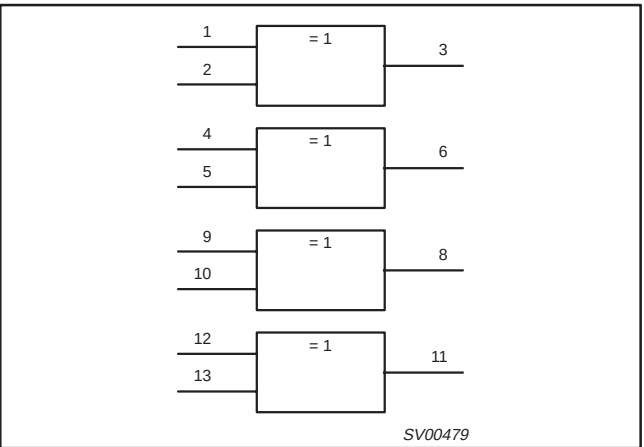
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
14-Pin Plastic DIL	-40°C to $+125^{\circ}\text{C}$	74LV86 N	74LV86 N	SOT27-1
14-Pin Plastic SO	-40°C to $+125^{\circ}\text{C}$	74LV86 D	74LV86 D	SOT108-1
14-Pin Plastic SSOP Type II	-40°C to $+125^{\circ}\text{C}$	74LV86 DB	74LV86 DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to $+125^{\circ}\text{C}$	74LV86 PW	74LV86PW DH	SOT402-1

PIN CONFIGURATION



LOGIC SYMBOL (IEEE/IEC)



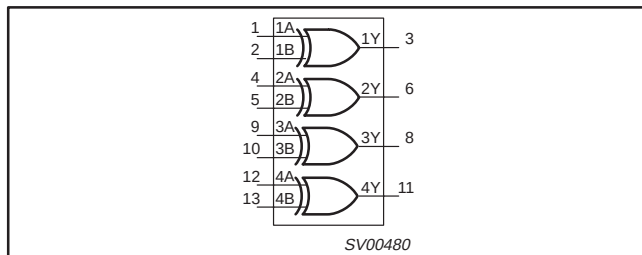
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PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1, 4, 9, 12	1A – 4A	Data inputs
2, 5, 10, 13	1B – 4B	Data inputs
3, 6, 8, 11	1Y – 4Y	Data outputs
7	GND	Ground (0 V)
14	V _{CC}	Positive supply voltage

LOGIC SYMBOL



FUNCTION TABLE

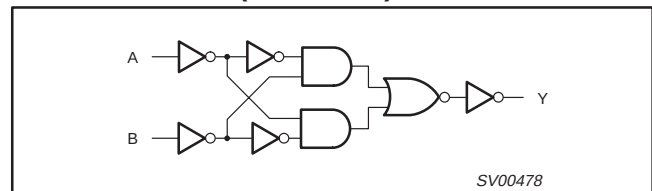
INPUTS		OUTPUTS
nA	nB	nY
L	L	L
L	H	H
H	L	H
H	H	L

NOTES:

H = HIGH voltage level

L = LOW voltage level

LOGIC DIAGRAM (ONE GATE)



RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CC}	DC supply voltage	See Note 1	1.0	3.3	5.5	V
V _I	Input voltage		0		V _{CC}	V
V _O	Output voltage		0		V _{CC}	V
T _{amb}	Operating ambient temperature range in free air	See DC and AC characteristics	–40 –40		+85 +125	°C
t _r , t _f	Input rise and fall times	V _{CC} = 1.0V to 2.0 V V _{CC} = 2.0V to 2.7 V V _{CC} = 2.7V to 3.6 V V _{CC} = 3.6V to 5.5 V			500 200 100 50	ns/V

NOTE:

- The LV is guaranteed to function down to V_{CC} = 1.0V (input levels GND or V_{CC}); DC characteristics are guaranteed from V_{CC} = 1.2V to V_{CC} = 5.5 V.

ABSOLUTE MAXIMUM RATINGS^{1, 2}

In accordance with the Absolute Maximum Rating System (IEC 134).

Voltages are referenced to GND (ground = 0V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		–0.5 to +7.0	V
±I _{IK}	DC input diode current	V _I < –0.5 or V _I > V _{CC} + 0.5V	20	mA
±I _{OK}	DC output diode current	V _O < –0.5 or V _O > V _{CC} + 0.5V	50	mA
±I _O	DC output source or sink current – standard outputs	–0.5V < V _O < V _{CC} + 0.5V	25	mA
±I _{GND} , ±I _{CC}	DC V _{CC} or GND current for types with – standard outputs		50	mA
T _{stg}	Storage temperature range		–65 to +150	°C
P _{TOT}	Power dissipation per package – plastic DIL – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: –40 to +125°C above +70°C derate linearly with 12 mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS					UNIT
			-40°C to +85°C			-40°C to +125°C		
			MIN	TYP ¹	MAX	MIN	MAX	
V _{IH}	HIGH level Input voltage	V _{CC} = 1.2 V	0.9			0.9		V
		V _{CC} = 2.0 V	1.4			1.4		
		V _{CC} = 2.7 to 3.6 V	2.0			2.0		
		V _{CC} = 4.5 to 5.5 V	0.7 * V _{CC}			0.7 * V _{CC}		
V _{IL}	LOW level Input voltage	V _{CC} = 1.2 V			0.3		0.3	V
		V _{CC} = 2.0 V			0.6		0.6	
		V _{CC} = 2.7 to 3.6 V			0.8		0.8	
		V _{CC} = 4.5 to 5.5			0.3 * V _{CC}		0.3 * V _{CC}	
V _{OH}	HIGH level output voltage; all outputs	V _{CC} = 1.2 V; V _I = V _{IH} or V _{IL} ; -I _O = 100µA		1.2				V
		V _{CC} = 2.0 V; V _I = V _{IH} or V _{IL} ; -I _O = 100µA	1.8	2.0		1.8		
		V _{CC} = 2.7 V; V _I = V _{IH} or V _{IL} ; -I _O = 100µA	2.5	2.7		2.5		
		V _{CC} = 3.0 V; V _I = V _{IH} or V _{IL} ; -I _O = 100µA	2.8	3.0		2.8		
		V _{CC} = 4.5 V; V _I = V _{IH} or V _{IL} ; -I _O = 100µA	4.3	4.5		4.3		
V _{OH}	HIGH level output voltage; STANDARD outputs	V _{CC} = 3.0 V; V _I = V _{IH} or V _{IL} ; -I _O = 6mA	2.40	2.82		2.20		V
		V _{CC} = 4.5 V; V _I = V _{IH} or V _{IL} ; -I _O = 12mA	3.60	4.20		3.50		
V _{OL}	LOW level output voltage; all outputs	V _{CC} = 1.2 V; V _I = V _{IH} or V _{IL} ; I _O = 100µA		0				V
		V _{CC} = 2.0 V; V _I = V _{IH} or V _{IL} ; I _O = 100µA		0	0.2		0.2	
		V _{CC} = 2.7 V; V _I = V _{IH} or V _{IL} ; I _O = 100µA		0	0.2		0.2	
		V _{CC} = 3.0 V; V _I = V _{IH} or V _{IL} ; I _O = 100µA		0	0.2		0.2	
		V _{CC} = 4.5 V; V _I = V _{IH} or V _{IL} ; I _O = 100µA		0	0.2		0.2	
V _{OL}	LOW level output voltage; STANDARD outputs	V _{CC} = 3.0 V; V _I = V _{IH} or V _{IL} ; I _O = 6mA		0.25	0.40		0.50	V
		V _{CC} = 4.5 V; V _I = V _{IH} or V _{IL} ; I _O = 12mA		0.35	0.55		0.65	
I _I	Input leakage current	V _{CC} = 5.5 V; V _I = V _{CC} or GND			1.0		1.0	µA
I _{CC}	Quiescent supply current; SSI	V _{CC} = 5.5V; V _I = V _{CC} or GND; I _O = 0			20.0		40	µA
ΔI _{CC}	Additional quiescent supply current per input	V _{CC} = 2.7 V to 3.6 V; V _I = V _{CC} -0.6 V			500		850	µA

NOTE:1. All typical values are measured at $T_{amb} = 25^\circ\text{C}$.**AC CHARACTERISTICS**GND = 0V; $t_r = t_f \leq 2.5\text{ns}$; $C_L = 50\text{pF}$; $R_L = 1\text{K}\Omega$

SYMBOL	PARAMETER	WAVEFORM	CONDITION	LIMITS					UNIT
				−40 to +85 °C			−40 to +125 °C		
			V _{CC} (V)	MIN	TYP ¹	MAX	MIN	MAX	
t _{PHL} /t _{PLH}	Propagation delay nA, nB to nY	Figure 1	1.2		70				ns
			2.0		24	32		41	
			2.7		18	24		30	
			3.0 to 3.6		13 ²	19		24	
			4.5 to 5.5			16		20	

NOTES:1. Unless otherwise stated, all typical values are measured at $T_{amb} = 25^\circ\text{C}$.2. Typical values are measured at $V_{CC} = 3.3\text{ V}$.

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AC WAVEFORMS

$V_M = 1.5\text{ V}$ at $V_{CC} \geq 2.7\text{ V}$ and $\leq 3.6\text{ V}$;
 $V_M = 0.5 \times V_{CC}$ at $V_{CC} < 2.7\text{ V}$ and $\geq 4.5\text{ V}$;
 V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.

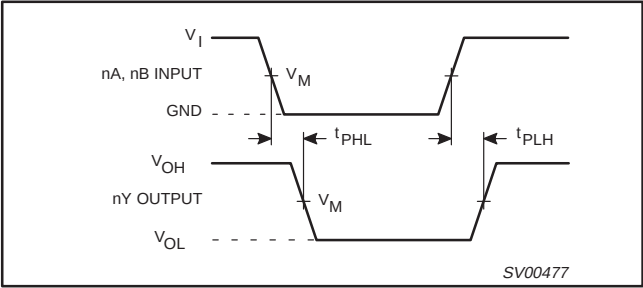


Figure 1. Input (nA, nB) to output (nY) propagation delays and the output transition times.

TEST CIRCUIT

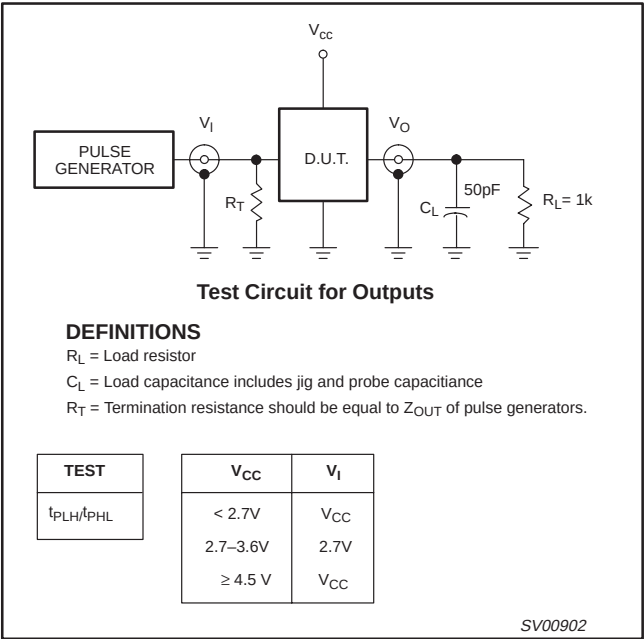


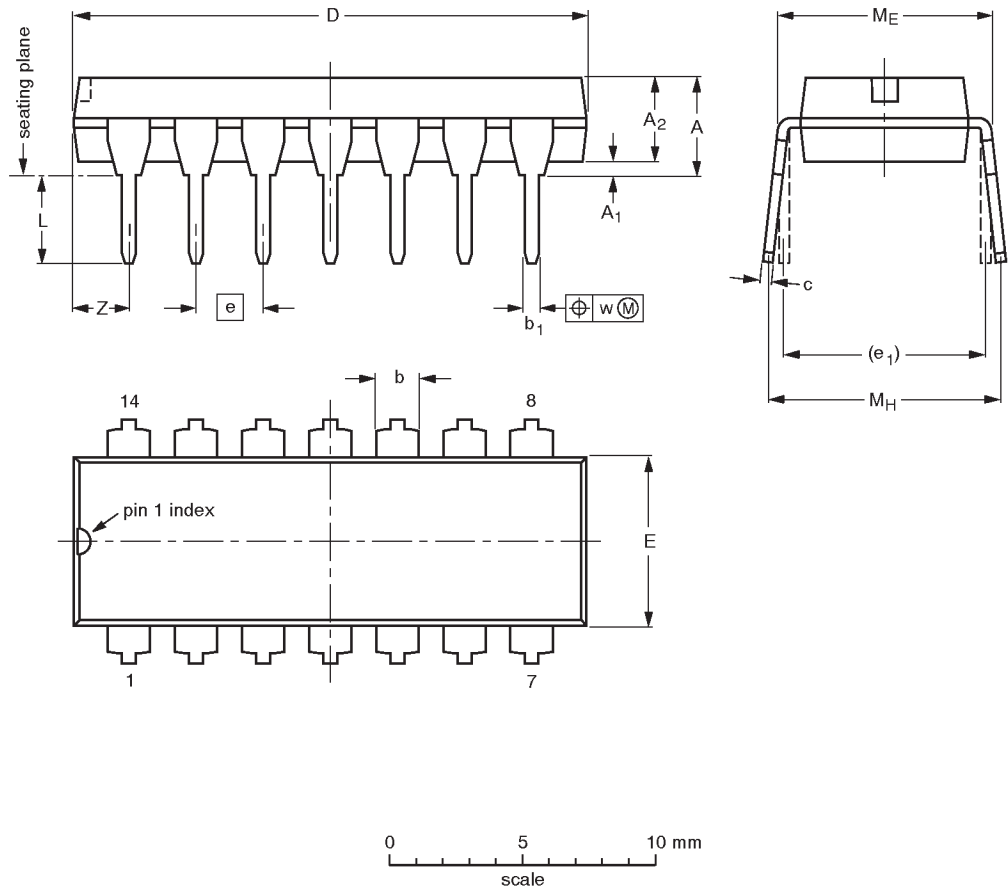
Figure 2. Load circuitry for switching times.

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DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	c	D ⁽¹⁾	E ⁽¹⁾	e	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

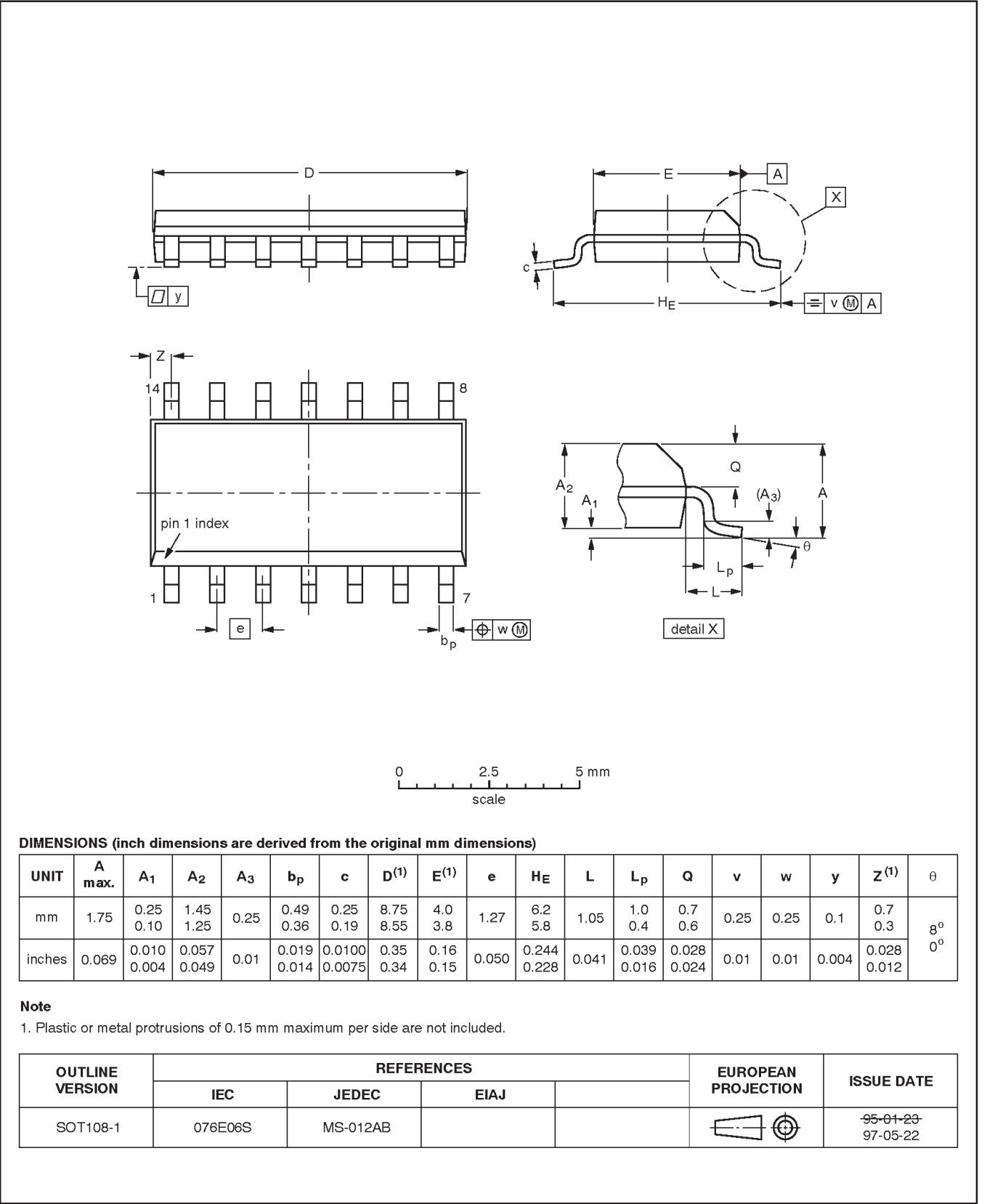
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT27-1	050G04	MO-001AA				92-11-17 95-03-11

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SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1

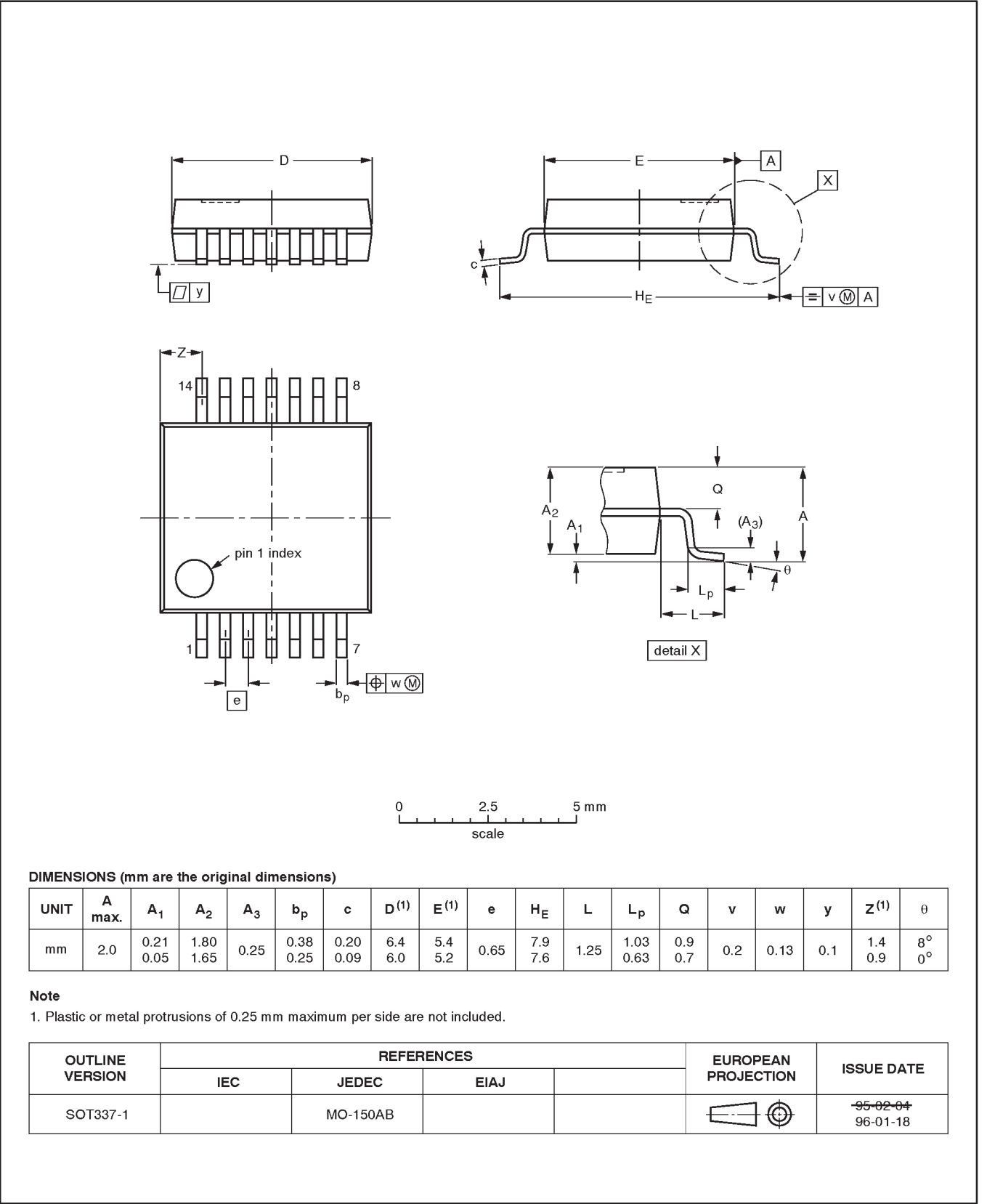


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SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1

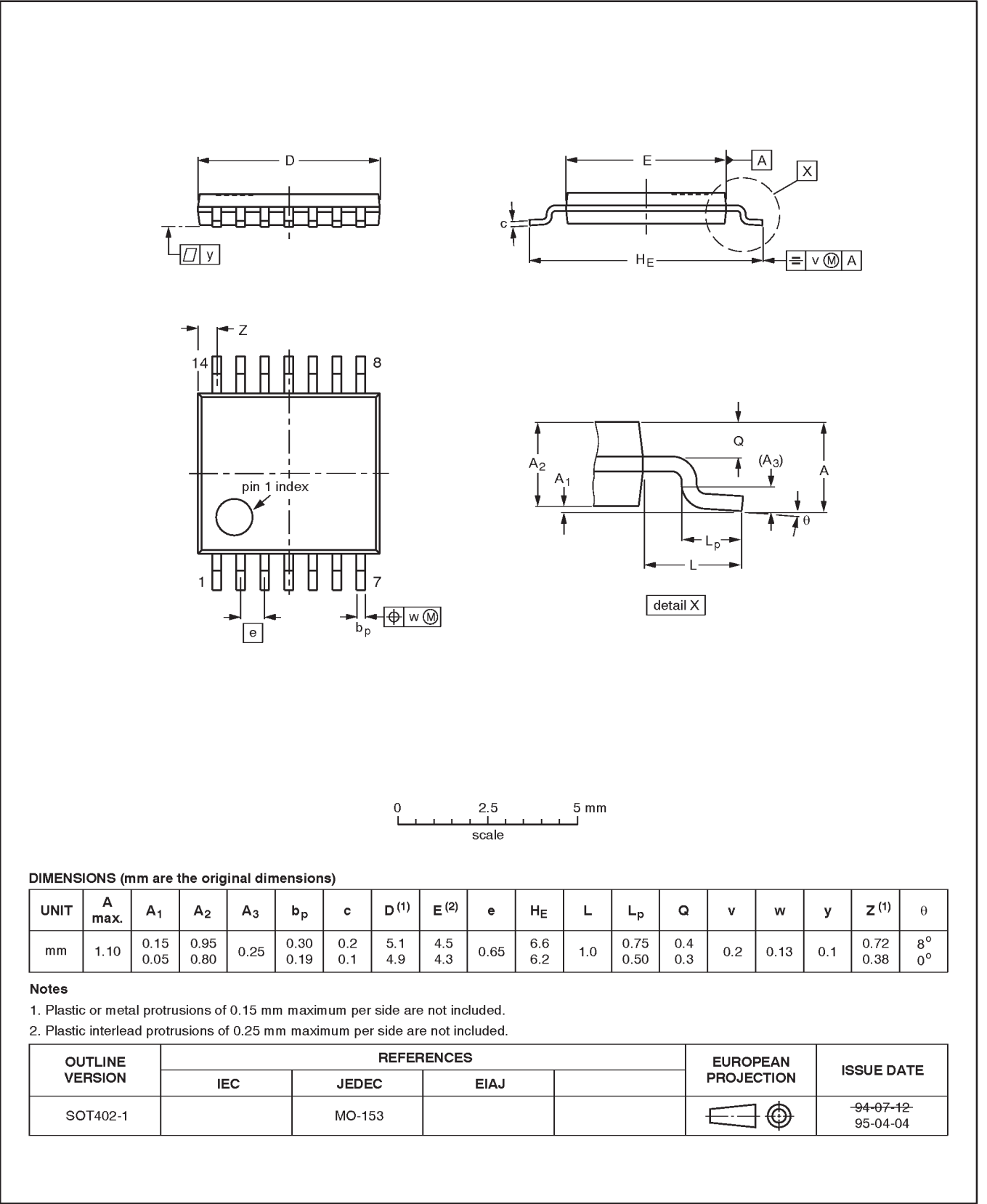


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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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[1] Please consult the most recently issued datasheet before initiating or completing a design.

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